

General description

The device is designed to protect high-speed interfaces such as SuperSpeed USB, High-Definition Multimedia Interface (HDMI), DisplayPort, external Serial Advanced Technology Attachment (eSATA) and Low Voltage Differential Signaling (LVDS) interfaces against ElectroStatic Discharge (ESD).

The device includes four high-level ESD protection diode structures for ultra high-speed signal lines and is encapsulated in a leadless small DFN2510-10L plastic package.

All signal lines are protected by a special diode configuration offering ultra low line capacitance of only 0.55 pF. These diodes utilize a unique snap-back structure in order to provide protection to downstream components from ESD voltages up to 15 kV contact exceeding IEC 61000-4-2, level 4.

Features and benefits

- System ESD protection for USB 2.0 and SuperSpeed USB 3.0, HDMI 2.0, DisplayPort, eSATA and LVDS
- All signal lines with integrated rail-to-rail clamping diodes for downstream ESD protection of 15 kV exceeding IEC 61000-4-2, level 4
- Matched 0.5 mm trace spacing
- Signal lines with 0.3 pF matching capacitance between signal pairs
- Line capacitance of only 0.5 pF for each channel
- Design-friendly 'pass-through' signal routing



DFN2510-10L

Application information

The device is designed for high-speed receiver and transmitter port protection:

- TVs and monitors (HDMI)
- DVD recorders and players
- Notebooks, main board graphic cards and ports
- Set-top boxes and game consoles
- SATA and eSATA Interface
- USB3.0

Ordering information

Device	Package	Reel Size	Qty(PCS)
RClamp0524PA	DFN2510-10L	7 Inch	3000

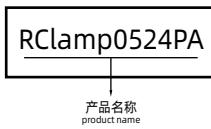
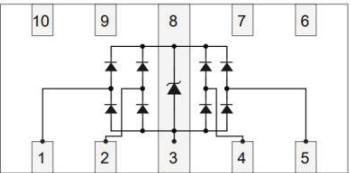


TWTLSEMI

TL-RClamp0524PA

DFN2510-10L 4-Line ESD Protection Diode Array

Ordering information

Marking	Naming rule	Graphic symbol
0524P		

Maximum Ratings (TA = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20μs)	P _{PPM}	55	W
Peak Pulse Current(tp = 8/20μs)	I _{PPM}	4	A
Maximum lead temperature for soldering during 10s	T _L	260	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Operating Temperature Range	T _{op}	-40 to +125	°C
Maximum junction temperature	T _j	150	°C
ESD voltage IEC 61000-4-2 (air discharge)	V _{ESD}	20	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V _{ESD}	15	kV

Electrical Characteristics (TA = 25 °C, unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V _{RWM}	--	--	5.0	V	
Breakdown Voltage	V _{BR}	6	--	8.5	V	I _T =1mA
Leakage Current I _{Leak}	I _R	--	--	100	nA	V _{RWM} =5V
Clamping Voltage	V _c	--	--	13.0	V	I _{PP} =4A, T _p =8/20μs
Junction Capacitance	C _J	--	0.3	0.4	pF	V _R =0V, f=1MHz I/O to I/O
Junction Capacitance	C _J	--	0.5	0.7	pF	V _R =0V, f=1MHz I/O to GND

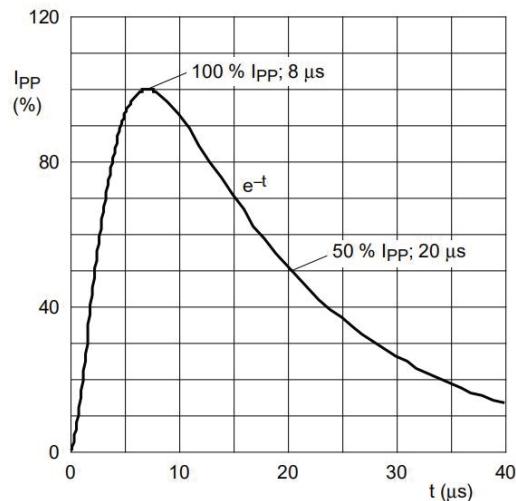
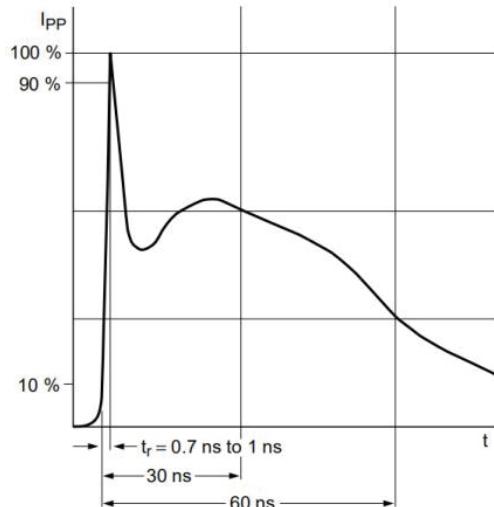


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DFN2510-10L 4-Line ESD Protection Diode Array

Typical Characteristics



Package Outline Dimensions

DFN2510-10L

